

### **Open-Drain Output Sub-Microamp Comparators**

#### Features

- Low Quiescent Current: 600 nA/comparator (typ.)
- Rail-to-Rail Input:  $V_{SS}$  0.3V to  $V_{DD}$  + 0.3V
- Open-Drain Output: V<sub>OUT</sub> ≤10V
- Propagation Delay 4 µs (typ.)
- Wide Supply Voltage Range: 1.6V to 5.5V
- · Single available in SOT-23-5, SC-70-5 packages
- Available in Single, Dual and Quad
- Chip Select (CS) with MCP6548
- · Low Switching Current
- Internal Hysteresis: 3.3 mV (typ.)
- Industrial Temperature: -40°C to +85°C

#### **Typical Applications**

- · Laptop Computers
- Mobile Phones
- Metering Systems
- · Hand-held Electronics
- RC Timers
- Alarm and Monitoring Circuits
- Windowed Comparators
- Multi-vibrators

#### **Related Devices**

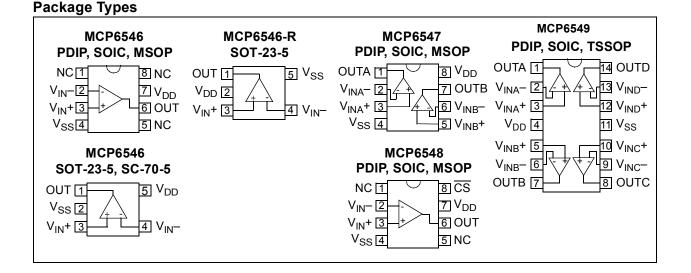
CMOS/TTL-Compatible Output: MCP6541/2/3/4

#### Description

The Microchip Technology Inc. MCP6546/7/8/9 family of comparators is offered in single (MCP6546), single with chip select (MCP6548), dual (MCP6547) and quad (MCP6549) configurations. The outputs are open-drain and are capable of driving heavy DC or capacitive loads.

These comparators are optimized for low power, single-supply application with greater than rail-to-rail input operation. The output limits supply current surges and dynamic power consumption while switching. The open-drain output of the MCP6546/7/8/9 family can be used as a level-shifter for up to 10V using a pull-up resistor. It can also be used as a wired-OR logic. The internal Input hysteresis eliminates output switching due to internal noise voltage, reducing current draw. These comparators operate with a single-supply voltage as low as 1.6V and draw less than 1  $\mu$ A/ comparator of quiescent current.

The related MCP6541/2/3/4 family of comparators from Microchip has a push-pull output that supports rail-to-rail output swing and interfaces with CMOS/TTL logic.



#### 1.0 ELECTRICAL CHARACTERISTICS

#### 1.1 Absolute Maximum Ratings †

V <sub>DD</sub> - V <sub>SS</sub>
Open-Drain outputV <sub>SS</sub> +10.5V
All inputs and outputs $V_{SS}$ –0.3V to $V_{DD}$ +0.3V
Difference Input voltage $ V_{DD} - V_{SS} $
Output Short-Circuit Currentcontinuous
Current at Input Pins±2 mA
Current at Output and Supply Pins±30 mA
Storage temperature65°C to +150°C
Maximum Junction Temperature (T <sub>J</sub> )+150°C
ESD protection on all pins (HBM;MM)4 kV;200V

**† Notice:** Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

#### **PIN FUNCTION TABLE**

NAME	FUNCTION
$V_{IN+,V_{INA}+,V_{INB}+,V_{INC}+,V_{IND}+}$	Non-Inverting Inputs
$V_{IN}$ -, $V_{INA}$ -, $V_{INB}$ -, $V_{INC}$ -, $V_{IND}$ -	Inverting Inputs
V <sub>DD</sub>	Positive Power Supply
V <sub>SS</sub>	Negative Power Supply
OUT, OUTA, OUTB, OUTC, OUTD	Outputs
CS	Chip Select
NC	Not Connected

#### DC CHARACTERISTICS

Parameters	Sym	Min	Тур	Max	Units	Conditions
	Oyin	IVIIII	тур	Max	Units	Conditions
Power Supply						
Supply Voltage	V <sub>DD</sub>	1.6	—	5.5	V	
Quiescent Current per comparator	۱ <sub>Q</sub>	0.3	0.6	1	μA	I <sub>OUT</sub> = 0
Input						
Input Voltage Range	V <sub>CMR</sub>	$V_{\rm SS}-0.3$	—	$V_{DD} + 0.3$	V	
Common Mode Rejection Ratio	CMRR	55	70	_	dB	$V_{DD}$ = 5V, $V_{CM}$ = -0.3V to 5.3V
Common Mode Rejection Ratio	CMRR	50	65		dB	$V_{DD}$ = 5V, $V_{CM}$ = 2.5V to 5.3V
Common Mode Rejection Ratio	CMRR	55	70	-	dB	$V_{DD}$ = 5V, $V_{CM}$ = -0.3V to 2.5V
Power Supply Rejection Ratio	PSRR	63	80		dB	$V_{CM} = V_{SS}$
Input Offset Voltage	V <sub>OS</sub>	-7.0	±1.5	+7.0	mV	V <sub>CM</sub> = V <sub>SS</sub> (Note 1)
Drift with Temperature	$\Delta V_{OS} / \Delta T_A$	—	±3		µV/°C	$T_A = -40^{\circ}C$ to +85°C, $V_{CM} = V_{SS}$
Input Hysteresis Voltage	V <sub>HYST</sub>	1.5	3.3	6.5	mV	V <sub>CM</sub> = V <sub>SS</sub> (Note 1)
Drift with Temperature	$\Delta V_{HYST} / \Delta T_A$	—	10	_	µV/°C	$T_A$ = -40°C to +25°C, $V_{CM}$ = $V_{SS}$
Drift with Temperature	$\Delta V_{HYST} / \Delta T_A$	—	5		µV/°C	$T_A = +25^{\circ}C$ to +85°C, $V_{CM} = V_{SS}$
Input Bias Current	I <sub>B</sub>	—	1		pА	$V_{CM} = V_{SS}$
Over Temperature	I <sub>B</sub>	—		100	pА	$T_A = -40^{\circ}C$ to +85°C, $V_{CM} = V_{SS}$ (Note 3)
Input Offset Current	I <sub>OS</sub>	—	±1	_	pА	$V_{CM} = V_{SS}$
Common Mode Input Impedance	Z <sub>CM</sub>	—	10 <sup>13</sup>   4	_	Ω  pF	
Differential Input Impedance	Z <sub>DIFF</sub>	_	10 <sup>13</sup>   2	_	Ω  pF	
Open-Drain Output						
Output Pull-Up Voltage	V <sub>PU</sub>	V <sub>DD</sub>		10	V	(Note 2)
High-Level Output Current	I <sub>ОН</sub>	-100	—	—	nA	V <sub>DD</sub> = 1.6V to 5.5V, V <sub>PU</sub> = 10V (Note 2)
Low-Level Output Voltage	V <sub>OL</sub>	V <sub>SS</sub>	—	V <sub>SS</sub> + 0.2	V	$I_{OUT}$ = 2 mA, $V_{PU}$ = $V_{DD}$ = 5V
Short-Circuit Current	I <sub>SC</sub>	—	±50	—	mA	V <sub>PU</sub> = V <sub>DD</sub> = 5.0V (Note 2)
Output Pin Capacitance	C <sub>OUT</sub>	_	8	_	рF	

**Note 1:** The input offset voltage is the center of the input-referred trip points. The input hysteresis is the difference between the input-referred trip points.

2: Do not short the output above  $V_{SS}$  + 10V. Limit the output current to Absolute Maximum Rating of 30 mA. The comparator does not function properly when  $V_{PU} < V_{DD}$ .

**3:** Input bias current overtemperature is not tested for the SC-70-5 package.

#### **AC CHARACTERISTICS**

<b>Electrical Specifications:</b> Unless otherwise indicated, $V_{DD}$ = +1.6V to +5.5V, $V_{SS}$ = GND, $T_A$ = 25°C, $V_{IN}$ + = $V_{DD}/2$ , Step = 200 mV, Overdrive = 100 mV, $R_{PU}$ = 2.74 k $\Omega$ to $V_{PU}$ = $V_{DD}$ , and $C_L$ = 36 pF (Refer to Figure 1-2 and Figure 1-3).								
Parameters	Sym	Min Typ Max Units Conditions						
Fall Time	t <sub>F</sub>		0.7	—	μs	(Note 1)		
Propagation Delay (High-to-Low)	t <sub>PHL</sub>	_	4.0	8.0	μs			
Propagation Delay (Low-to-High)	t <sub>PLH</sub>	_	3.0	8.0	μs	(Note 1)		
Propagation Delay Skew	t <sub>PDS</sub>	_	-1.0	—	μs	(Notes 1 and 2)		
Maximum Toggle Frequency	f <sub>MAX</sub>	_	225	—	kHz	V <sub>DD</sub> = 1.6V		
	f <sub>MAX</sub>	_	165	_	kHz	V <sub>DD</sub> = 5.5V		
Input Noise Voltage	E <sub>N</sub>		200	—	$\mu V_{P-P}$	10 Hz to 100 kHz		

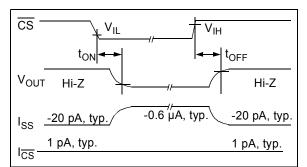
Note 1: t<sub>R</sub> and t<sub>PLH</sub> depend on the load (R<sub>L</sub> and C<sub>L</sub>); these specifications are valid for the indicated load only.

**2:** Propagation Delay Skew is defined as:  $t_{PDS} = t_{PLH} - t_{PHL}$ .

#### SPECIFICATIONS FOR MCP6548 CHIP SELECT

**Electrical Specifications:** Unless otherwise indicated,  $V_{DD}$  = +1.6V to +5.5V,  $V_{SS}$  = GND,  $T_A$  = 25°C,  $V_{IN}$  =  $V_{DD}/2$ ,  $V_{IN}$  =  $V_{SS}$ ,  $R_{PU}$  = 2.74 k $\Omega$  to  $V_{PU}$  =  $V_{DD}$ , and  $C_L$  = 36 pF (Refer to Figures 1-1 and 1-3).

Parameters	Sym	Min	Тур	Max	Units	Conditions
CS Low Specifications						
CS Logic Threshold, Low	V <sub>IL</sub>	$V_{SS}$	—	$0.2V_{DD}$	V	
CS Input Current, Low	I <sub>CSL</sub>	_	5	—	pА	$\overline{CS} = V_{SS}$
CS High Specifications						
CS Logic Threshold, High	V <sub>IH</sub>	0.8V <sub>DD</sub>		V <sub>DD</sub>	V	
CS Input Current, High	I <sub>CSH</sub>	_	1	—	pА	$\overline{CS} = V_{DD}$
CS Input High, V <sub>DD</sub> Current	I <sub>DD</sub>	_	18	—	pА	$\overline{CS} = V_{DD}$
CS Input High, GND Current	I <sub>SS</sub>	_	-20	—	pА	$\overline{CS} = V_{DD}$
Comparator Output Leakage	I <sub>O(LEAK)</sub>	_	1	—	pА	V <sub>OUT</sub> = V <sub>SS</sub> +10V
CS Dynamic Specifications						
CS Low to Comparator Output Low Turn-on Time	t <sub>ON</sub>	_	2	50	ms	$\overline{\text{CS}}$ = 0.2V <sub>DD</sub> to V <sub>OUT</sub> = V <sub>DD</sub> /2, V <sub>IN</sub> - = V <sub>DD</sub>
CS High to Comparator Output High Z Turn-off Time	t <sub>OFF</sub>	—	10	—	μs	$\overline{\text{CS}}$ = 0.8V <sub>DD</sub> to V <sub>OUT</sub> = V <sub>DD</sub> /2, V <sub>IN</sub> - = V <sub>DD</sub>
CS Hysteresis	V <sub>CS_HYST</sub>		0.6	_	V	V <sub>DD</sub> = 5V



**FIGURE 1-1:** Timing Diagram for the  $\overline{CS}$  pin on the MCP6548.

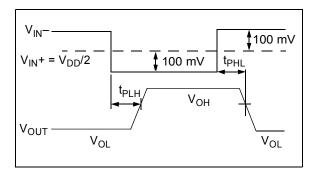


FIGURE 1-2: Propagation Delay Timing Diagram.

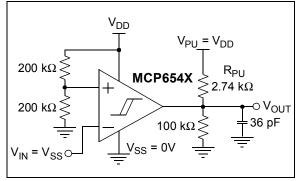
#### **TEMPERATURE SPECIFICATIONS**

Electrical Specifications: Unless otherwise indicated, $V_{DD}$ = +1.6V to +5.5V and $V_{SS}$ = GND.								
Parameters	Sym	Min	Тур	Мах	Units	Conditions		
Temperature Ranges								
Specified Temperature Range	T <sub>A</sub>	-40	_	+85	°C			
Operating Temperature Range	T <sub>A</sub>	-40	—	+125	°C	Note		
Storage Temperature Range	T <sub>A</sub>	-65	_	+150	°C			
Thermal Package Resistances								
Thermal Resistance, 5L-SC-70	$\theta_{JA}$	_	331	-	°C/W			
Thermal Resistance, 5L-SOT-23	$\theta_{JA}$	_	256	_	°C/W			
Thermal Resistance, 8L-PDIP	$\theta_{JA}$	_	85	_	°C/W			
Thermal Resistance, 8L-SOIC	$\theta_{JA}$	_	163	—	°C/W			
Thermal Resistance, 8L-MSOP	$\theta_{JA}$	_	206	_	°C/W			
Thermal Resistance, 14L-PDIP	$\theta_{JA}$	_	70	_	°C/W			
Thermal Resistance, 14L-SOIC	$\theta_{JA}$	_	120	—	°C/W			
Thermal Resistance, 14L-TSSOP	$\theta_{JA}$		100		°C/W			

**Note:** The MCP6546/7/8/9 operates over this extended temperature range, but with reduced performance. In any case, the Junction Temperature  $(T_J)$  must not exceed the absolute maximum specification of +150°C.

#### 1.2 Test Circuit Configuration

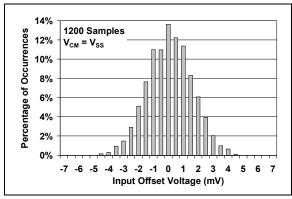
This test circuit configuration is used to determine the AC and DC specifications.



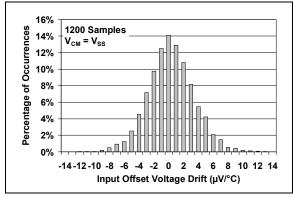
**FIGURE 1-3:** AC and DC Test circuit for the open- drain output comparators.

#### 2.0 TYPICAL PERFORMANCE CURVES

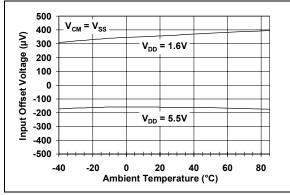
**Note:** The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.



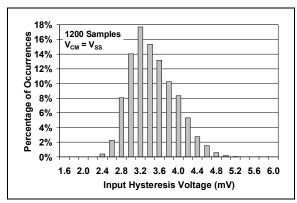
**FIGURE 2-1:** Input Offset Voltage Histogram at  $V_{CM} = V_{SS}$ .



**FIGURE 2-2:** Input Offset Voltage Drift Histogram at  $V_{CM} = V_{SS}$ .



**FIGURE 2-3:** Input Offset Voltage vs. Ambient Temperature at  $V_{CM} = V_{SS}$ .



**FIGURE 2-4:** Input Hysteresis Voltage Histogram at  $V_{CM} = V_{SS}$ .

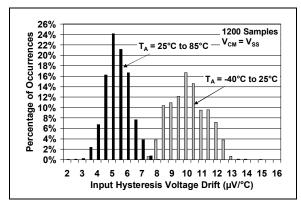
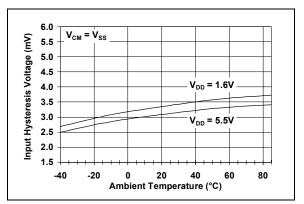


FIGURE 2-5: Input Hysteresis Voltage Drift Histogram.



**FIGURE 2-6:** Input Hysteresis Voltage vs. Ambient Temperature at  $V_{CM} = V_{SS}$ .

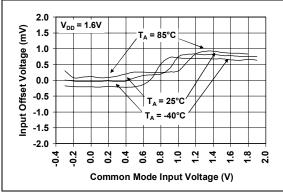
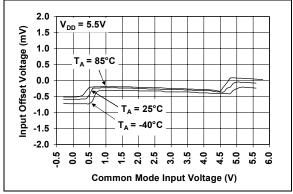
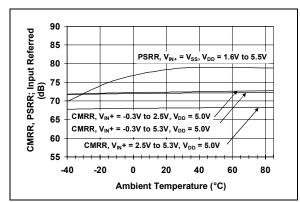


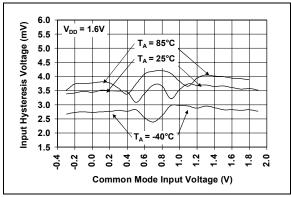
FIGURE 2-7:Input Offset Voltage vs.Common Mode Input Voltage at  $V_{DD} = 1.6V.$ 



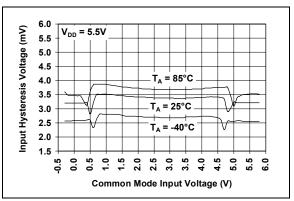
**FIGURE 2-8:** Input Offset Voltage vs. Common Mode Input Voltage at  $V_{DD}$  = 5.5V.



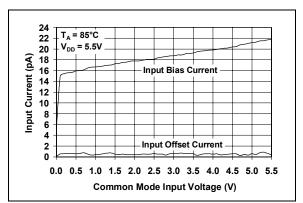
**FIGURE 2-9:** CMRR, PSRR vs. Ambient Temperature at  $V_{CM} = V_{SS}$ .



**FIGURE 2-10:** Input Hysteresis Voltage vs. Common Mode Input Voltage at  $V_{DD} = 1.6V$ .



**FIGURE 2-11:** Input Hysteresis Voltage vs. Common Mode Input Voltage at  $V_{DD}$  = 5.5V.



**FIGURE 2-12:** Input Bias Current, Input Offset Current vs. Common Mode Input Voltage at +85°C.

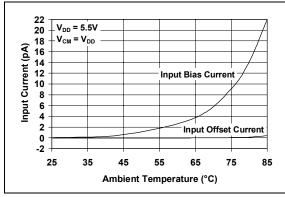


FIGURE 2-13: Input Bias Current, Input Offset Current vs. Ambient Temperature.

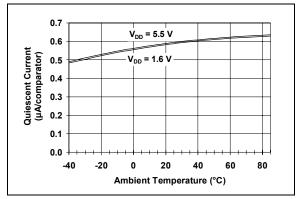
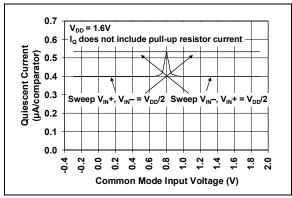
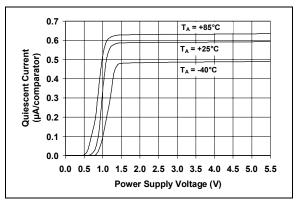
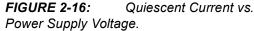


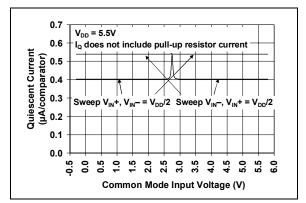
FIGURE 2-14: Quiescent Current vs. Ambient Temperature vs. Power Supply Voltage.



**FIGURE 2-15:** Quiescent Current vs. Common Mode Input Voltage at  $V_{DD} = 1.6V$ .







**FIGURE 2-17:** Quiescent Current vs. Common Mode Input Voltage at  $V_{DD} = 5V$ .

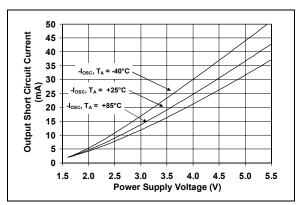
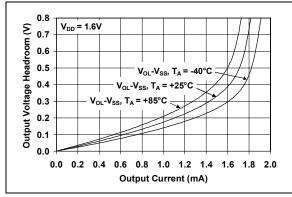
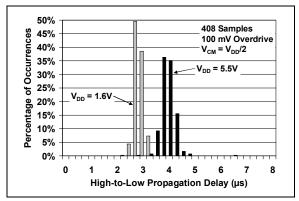


FIGURE 2-18: Output Short-Circuit Current vs. Power Supply Voltage.



**FIGURE 2-19:** Output Voltage Headroom vs. Output Current at  $V_{DD} = 1.6V$ .



*FIGURE 2-20:* High-to-Low Propagation Delay Histogram.

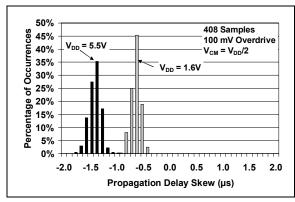
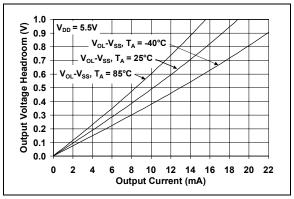
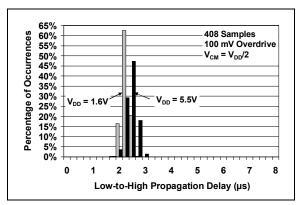


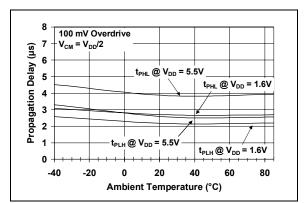
FIGURE 2-21: Propagation Delay Skew Histogram.



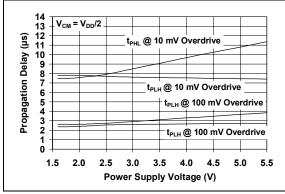
**FIGURE 2-22:** Output Voltage Headroom vs. Output Current at  $V_{DD} = 5.5V$ .



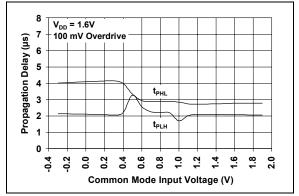
*FIGURE 2-23:* Low-to-High Propagation Delay Histogram.



**FIGURE 2-24:** Propagation Delay vs. Ambient Temperature.



**FIGURE 2-25:** Propagation Delay vs. Power Supply Voltage.



**FIGURE 2-26:** Propagation Delay vs. Common Mode Input Voltage at  $V_{DD}$  = 1.6V.

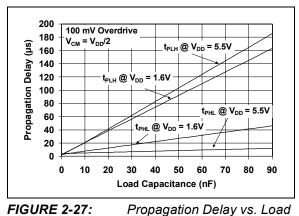


FIGURE 2-27: Capacitance.

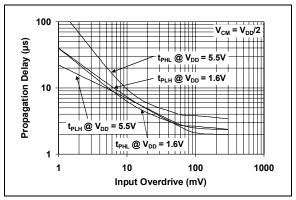
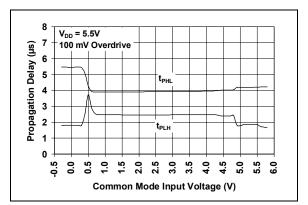


FIGURE 2-28: Propagation Delay vs. Input Overdrive.



**FIGURE 2-29:** Propagation Delay vs. Common Mode Input Voltage at  $V_{DD}$  = 5.5V.

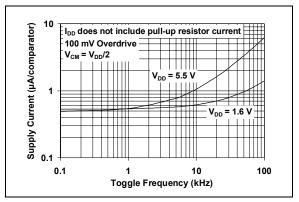


FIGURE 2-30: Supply Current vs. Toggle Frequency.

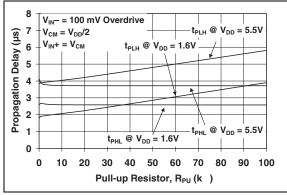
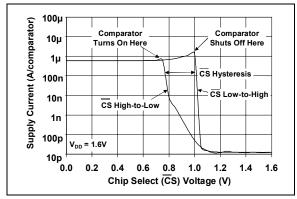
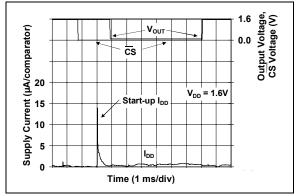


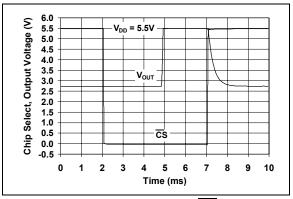
FIGURE 2-31: Propagation Delay vs. Pullup Resistor.



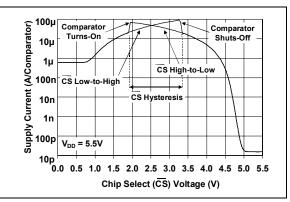
**FIGURE 2-32:** Supply Current (shoot through current) vs. Chip Select ( $\overline{CS}$ ) Voltage at  $V_{DD}$  = 1.6V (MCP6548 only).



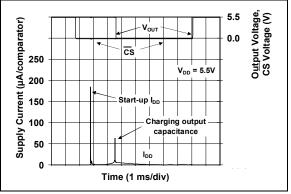
**FIGURE 2-33:** Supply Current (charging current) vs. Chip Select (CS) pulse at  $V_{DD}$  = 1.6V (MCP6548 only).



**FIGURE 2-34:** Chip Select ( $\overline{CS}$ ) Step Response (MCP6548 only).

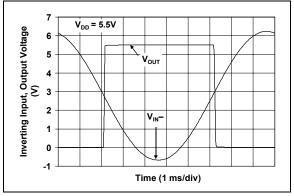


**FIGURE 2-35:** Supply Current (shoot through current) vs. Chip Select (CS) Voltage at  $V_{DD}$  = 5.5V (MCP6548 only).



**FIGURE 2-36:** Supply Current (charging current) vs. Chip Select (CS) pulse at  $V_{DD}$  = 5.5V (MCP6548 only).

**Note:** Unless otherwise indicated,  $V_{DD}$  = +1.6V to +5.0V,  $V_{SS}$  = GND,  $T_A$  = +25°C,  $V_{IN}$ + =  $V_{DD}/2$ ,  $V_{IN}$ - = GND,  $R_{PU}$  = 2.74 k $\Omega$  to  $V_{PU}$  =  $V_{DD}$ , and  $C_L$  = 36 pF.



**FIGURE 2-37:** The MCP6546/7/8/9 comparators show no phase reversal.

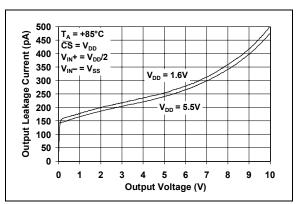


FIGURE 2-38:Output Leakage Current $(CS = V_{DD})$  vs. Output Voltage (MCP6548 only)

#### 3.0 APPLICATIONS INFORMATION

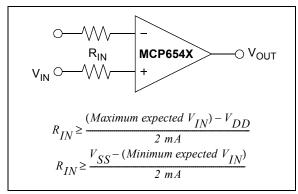
The MCP6546/7/8/9 family of push-pull output comparators are fabricated on Microchip's state-of-theart CMOS process. They are suitable for a wide range of applications requiring very low power consumption.

#### 3.1 Comparator Inputs

The MCP6546/7/8/9 comparator family uses CMOS transistors at the input. They are designed to prevent phase inversion when the input pins exceed the supply voltages. Figure 2-37 shows an input voltage exceeding both supplies with no resulting phase inversion.

The input stage of this family of devices uses two differential input stages in parallel: one operates at low input voltages and the other at high input voltages. With this topology, the input voltage is 0.3V above V<sub>DD</sub> and 0.3V below V<sub>SS</sub>. Therefore, the input offset voltage is measured at both V<sub>SS</sub>-0.3V and V<sub>DD</sub> + 0.3V to ensure proper operation.

The maximum operating input voltages that can be applied are  $V_{SS}$  - 0.3V and  $V_{DD}$  + 0.3V. Voltages on the inputs that exceed this absolute maximum rating can cause excessive current to flow and permanently damage the device. In applications where the input pin exceeds the specified range, external resistors can be used to limit the current below ±2 mA, as shown in Figure 3-1.



**FIGURE 3-1:** An input resistor  $(R_{IN})$  should be used to limit excessive input current if either of the inputs exceeds the absolute maximum specification.

#### 3.2 Open-Drain Output

The open-drain output is designed to make levelshifting and wired-OR logic easy to implement. The output can go as high as 10V for 9V battery-powered applications. The output stage minimizes switching current (shoot-through current from supply-to-supply) when the output changes state. See Figures 2-15, 2-17 and 2-32 through 2-36, for more information.

#### 3.3 MCP6548 Chip Select (CS)

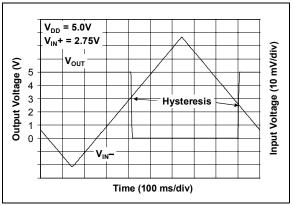
The MCP6548 is a single comparator with a chip select (CS) option. When CS is pulled high, the total current consumption drops to 20 pA (typ). 1 pA (typ) flows through the CS pin, 1 pA (typ) flows through the output pin and 18 pA (typ) flows through the  $V_{DD}$  pin, as shown in Figure 1-1. When this happens, the comparator output is put into a high-impedance state. By pulling CS low, the comparator is enabled. If the CS pin is left floating, the comparator will not operate properly. Figure 1-1 shows the output voltage and supply current response to a CS pulse.

The internal  $\overline{CS}$  circuitry is designed to minimize glitches when cycling the  $\overline{CS}$  pin. This helps conserve power, which is especially important in battery-powered applications.

#### 3.4 Externally Set Hysteresis

Greater flexibility in selecting hysteresis, or input trip points, is achieved by using external resistors.

Input offset voltage (V<sub>OS</sub>) is the center (average) of the (input-referred) low-high and high-low trip points. Input hysteresis voltage (V<sub>HYST</sub>) is the difference between the same trip points. Hysteresis reduces output chattering when one input is slowly moving past the other, thus reducing dynamic supply current. It also helps in systems where it is best not to cycle between states too frequently (e.g., air conditioner thermostatic control). The MCP6546/7/8/9 family has internally-set hysteresis that is small enough to maintain input offset accuracy (<7 mV), and large enough to eliminate output chattering caused by the comparator's own input noise voltage (200  $\mu$ Vp-p).



**FIGURE 3-2:** The MCP6546/7/8/9 comparators' internal hysteresis eliminates output chatter caused by input noise voltage.

#### 3.4.1 INVERTING CIRCUIT

Figure 3-3 shows an inverting circuit for a single-supply application using three resistors, besides the pull-up resistor. The resulting hysteresis diagram is shown in Figure 3-4.

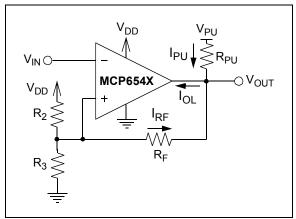


FIGURE 3-3: Inverting circuit with hysteresis.

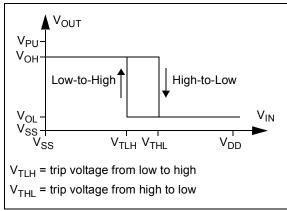


FIGURE 3-4: Hysteresis diagram for the inverting circuit.

In order to determine the trip voltages ( $V_{THL}$  and  $V_{TLH}$ ) for the circuit shown in Figure 3-3,  $R_2$  and  $R_3$  can be simplified to the Thevenin equivalent circuit with respect to  $V_{DD}$ , as shown in Figure 3-5.

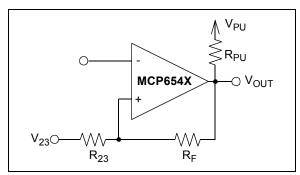


FIGURE 3-5:

Thevenin Equivalent Circuit.

Where:

$$R_{23} = \frac{R_2 R_3}{R_2 + R_3}$$
$$V_{23} = \frac{R_3}{R_2 + R_3} \times V_{DD}$$

Using this simplified circuit, the trip voltage can be calculated using the following equation:

#### EQUATION

$$V_{THL} = V_{PU} \left( \frac{R_{23}}{R_{23} + R_F + R_{PU}} \right) + V_{23} \left( \frac{R_F + R_{PU}}{R_{23} + R_F + R_{PU}} \right)$$
$$V_{TLH} = V_{OL} \left( \frac{R_{23}}{R_{23} + R_F} \right) + V_{23} \left( \frac{R_F}{R_{23} + R_F} \right)$$

 $V_{TLH}$  = trip voltage from low to high

 $V_{THL}$  = trip voltage from high to low

Figure 2-19 and Figure 2-22 can be used to determine typical values for V<sub>OL</sub>. This voltage is dependent on the output current I<sub>OL</sub> as shown in Figure 3-3. This current can be determined using the equation below:

#### EQUATION

$$\begin{split} I_{OL} &= I_{PU} + I_{RF} \\ I_{OL} &= \left(\frac{V_{PU} - V_{OL}}{R_{PU}}\right) + \left(\frac{V_{23} - V_{OL}}{R_{23} + R_{F}}\right) \end{split}$$

V<sub>OH</sub> can be calculated using the equation below:

#### EQUATION

$$V_{OH} = (V_{PU} - V_{23}) \times \left(\frac{R_{23} + R_F}{R_{23} + R_F + R_{PU}}\right)$$

As explained in Section 3.1, "Comparator Inputs", it is important to keep the non-inverting input below  $V_{DD}$ +0.3V when  $V_{PU}$  >  $V_{DD}$ .

#### 3.5 Supply Bypass

With this family of comparators, the power supply pin (V<sub>DD</sub> for single supply) should have a local bypass capacitor (i.e., 0.01  $\mu$ F to 0.1  $\mu$ F) within 2 mm for good edge rate performance.

#### 3.6 Capacitive Loads

Reasonable capacitive loads (e.g., logic gates) have little impact on propagation delay (see Figure 2-27). The supply current increases with increasing toggle frequency (Figure 2-30), especially with higher capacitive loads.

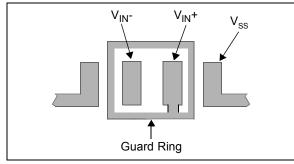
#### 3.7 Battery Life

In order to maximize battery life in portable applications, use large resistors and small capacitive loads. Also, avoid toggling the output more than necessary and do not use chip select  $(\overline{CS})$  to conserve power for short periods of time. Capacitive loads will draw additional power at start-up.

#### 3.8 PCB Surface Leakage

In applications where low input bias current is critical, PCB (Printed Circuit Board) surface leakage effects need to be considered. Surface leakage is caused by humidity, dust or other contamination on the board. Under low-humidity conditions, a typical resistance between nearby traces is  $10^{12}\Omega$ . A 5V difference would cause 5 pA. If current-to-flow, this is greater than the MCP6546/7/8/9 family's bias current at 25°C (1 pA, typ).

The easiest way to reduce surface leakage is to use a guard ring around sensitive pins (or traces). The guard ring is biased at the same voltage as the sensitive pin. An example of this type of layout is shown in Figure 3-6.



**FIGURE 3-6:** Example Guard Ring Layout for Inverting Circuit.

- 1. Inverting Configuration (Figures 3-3 and 3-6):
  - a. Connect the guard ring to the non-inverting input pin (V<sub>IN</sub>+). This biases the guard ring to the same reference voltage as the comparator (e.g.,  $V_{DD}/2$  or ground).
  - b. Connect the inverting pin (V\_{IN}-) to the input pad without touching the guard ring.

#### **3.9** Typical Applications

#### 3.9.1 PRECISE COMPARATOR

Some applications require higher DC precision. An easy way to solve this problem is to use an amplifier (such as the MCP6041) to gain-up the input signal before it reaches the comparator. Figure 3-7 shows an example of this approach.

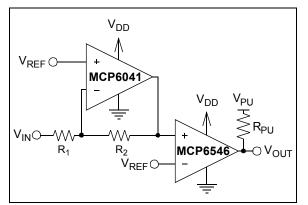
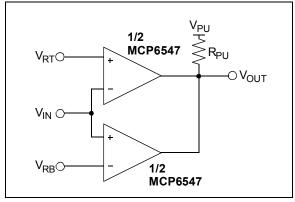
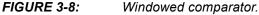


FIGURE 3-7: Precise Inverting Comparator.

#### 3.9.2 WINDOWED COMPARATOR

Figure 3-8 shows one approach to designing a windowed comparator. The wired-OR connection produces a high output (logic 1) when the input voltage is between  $V_{RB}$  and  $V_{RT}$  (where  $V_{RT} > V_{RB}$ ).

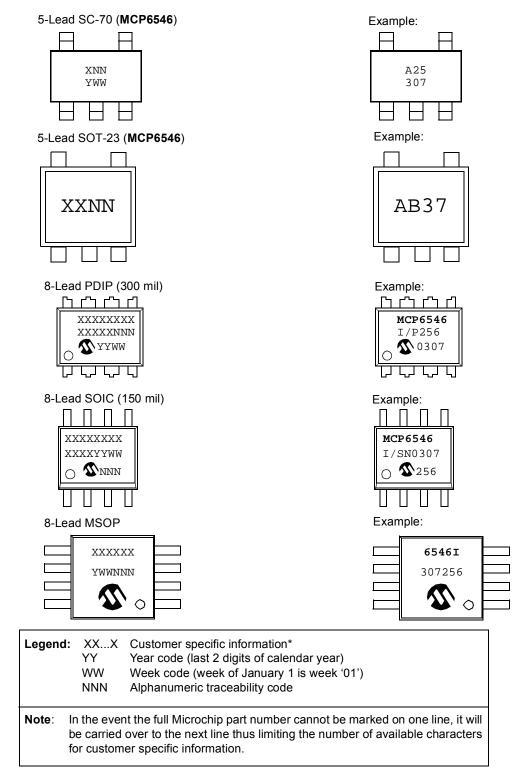




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#### 4.0 PACKAGING INFORMATION

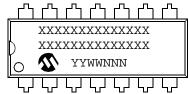
#### 4.1 Package Marking Information



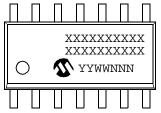
\* Standard marking consists of Microchip part number, year code, week code, traceability code (facility code, mask rev#, and assembly code). For marking beyond this, certain price adders apply. Please check with your Microchip Sales Office.

#### Package Marking Information (Continued)

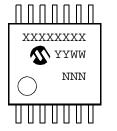
14-Lead PDIP (300 mil) (MCP6549)



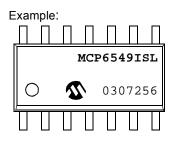
14-Lead SOIC (150 mil) (MCP6549)



14-Lead TSSOP (MCP6549)



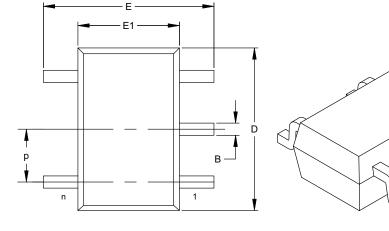
Example:

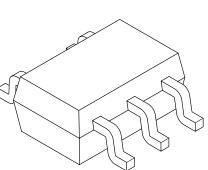


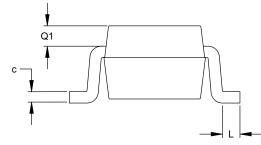
Example:

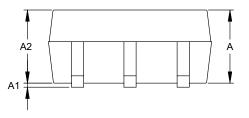


#### 5-Lead Plastic Package (LT) (SC-70)









	Units		INCHES		MILLIMETERS*		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		5			5	
Pitch	р		.026 (BSC)			0.65 (BSC)	
Overall Height	A	.031		.043	0.80		1.10
Molded Package Thickness	A2	.031		.039	0.80		1.00
Standoff	A1	.000		.004	0.00		0.10
Overall Width	E	.071		.094	1.80		2.40
Molded Package Width	E1	.045		.053	1.15		1.35
Overall Length	D	.071		.087	1.80		2.20
Foot Length	L	.004		.012	0.10		0.30
Top of Molded Pkg to Lead Shoulder	Q1	.004		.016	0.10		0.40
Lead Thickness	с	.004		.007	0.10		0.18
Lead Width	В	.006		.012	0.15		0.30

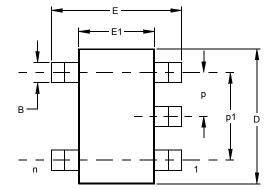
\*Controlling Parameter

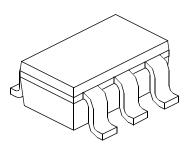
Notes:

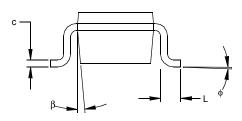
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side.

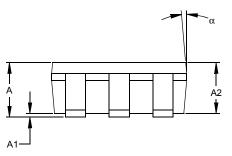
JEITA (EIAJ) Standard: SC-70 Drawing No. C04-061

5-Lead Plastic Small Outline Transistor (OT) (SOT23)









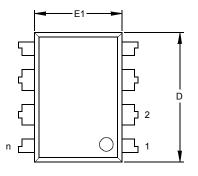
Units	INCHES*			MILLIMETERS		
on Limits	MIN	NOM	MAX	MIN	NOM	MAX
n		5			5	
р		.038			0.95	
p1		.075			1.90	
А	.035	.046	.057	0.90	1.18	1.45
A2	.035	.043	.051	0.90	1.10	1.30
A1	.000	.003	.006	0.00	0.08	0.15
Е	.102	.110	.118	2.60	2.80	3.00
E1	.059	.064	.069	1.50	1.63	1.75
D	.110	.116	.122	2.80	2.95	3.10
L	.014	.018	.022	0.35	0.45	0.55
φ	0	5	10	0	5	10
С	.004	.006	.008	0.09	0.15	0.20
В	.014	.017	.020	0.35	0.43	0.50
α	0	5	10	0	5	10
β	0	5	10	0	5	10
	n Limits n p p1 A A2 A1 E1 D L φ c B α	n Limits         MIN           n            p1            A         .035           A2         .035           A1         .000           E         .102           E1         .059           D         .110           L         .014           φ         0           c         .004           B         .014           α         0	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

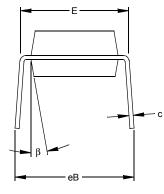
\* Controlling Parameter § Significant Characteristic

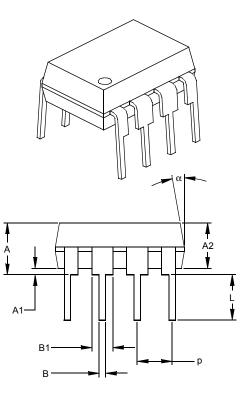
Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MO-178 Drawing No. C04-091

#### 8-Lead Plastic Dual In-line (P) – 300 mil (PDIP)







	Units		INCHES*		MILLIMETERS		
Dimensio	on Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.100			2.54	
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60
Overall Length	D	.360	.373	.385	9.14	9.46	9.78
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56
Overall Row Spacing §	eB	.310	.370	.430	7.87	9.40	10.92
Mold Draft Angle Top	а	5	10	15	5	10	15
Mold Draft Angle Bottom	b	5	10	15	5	10	15

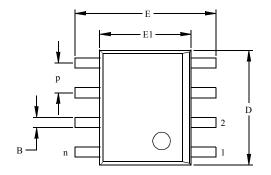
\* Controlling Parameter § Significant Characteristic

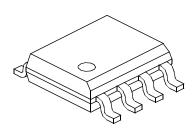
Notes:

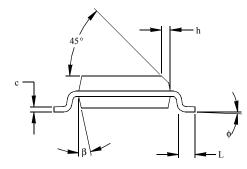
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-001 Drawing No. C04-018

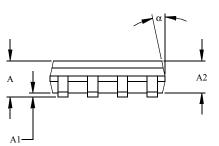
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8-Lead Plastic Small Outline (SN) - Narrow, 150 mil (SOIC)









	Units		INCHES*		MILLIMETERS		
Dimens	ion Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.050			1.27	
Overall Height	А	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	Е	.228	.237	.244	5.79	6.02	6.20
Molded Package Width	E1	.146	.154	.157	3.71	3.91	3.99
Overall Length	D	.189	.193	.197	4.80	4.90	5.00
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.019	.025	.030	0.48	0.62	0.76
Foot Angle	¢	0	4	8	0	4	8
Lead Thickness	с	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.013	.017	.020	0.33	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15
* Controlling Decemptor	Р	0	12	15	0	12	

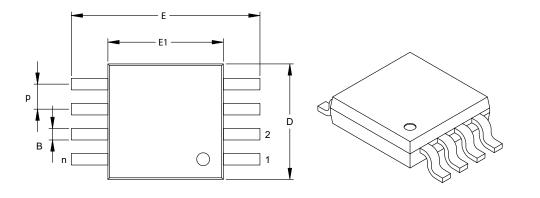
\* Controlling Parameter § Significant Characteristic

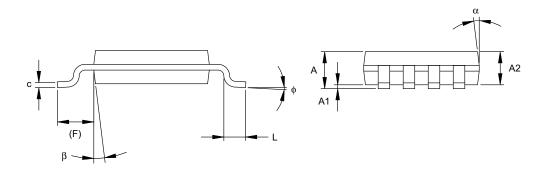
#### Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MS-012 Drawing No. C04-057

#### 8-Lead Plastic Micro Small Outline Package (MS) (MSOP)





	Units		INCHES		М	MILLIMETERS*		
Dimension L	imits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		8			8		
Pitch	р		.026 BSC			0.65 BSC		
Overall Height	A	-	-	.043	-	-	1.10	
Molded Package Thickness	A2	.030	.033	.037	0.75	0.85	0.95	
Standoff	A1	.000	-	.006	0.00	-	0.15	
Overall Width	E	.193 TYP.			4.90 BSC			
Molded Package Width	E1	.118 BSC			3.00 BSC			
Overall Length	D		.118 BSC		3.00 BSC			
Foot Length	L	.016	.024	.031	0.40	0.60	0.80	
Footprint (Reference)	F		.037 REF			0.95 REF		
Foot Angle	¢	0°	-	8°	0°	-	8°	
Lead Thickness	С	.003	.006	.009	0.08	-	0.23	
Lead Width	В	.009	.012	.016	0.22	-	0.40	
Mold Draft Angle Top	α	5°	-	15°	5°	-	15°	
Mold Draft Angle Bottom	β	5°	-	15°	5°	-	15°	
*Controlling Parameter								

\*Controlling Parameter

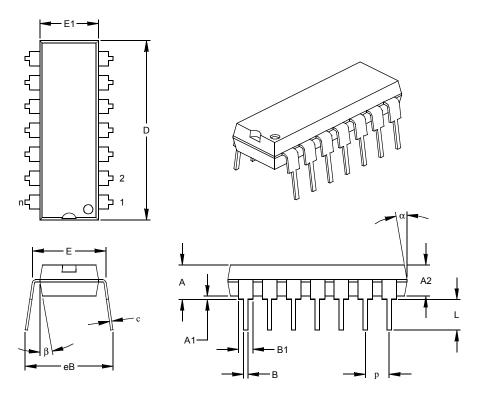
Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MO-187

Drawing No. C04-111

14-Lead Plastic Dual In-line (P) – 300 mil (PDIP)



	Units		INCHES*		MILLIMETERS			
Dimensio	n Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		14			14		
Pitch	р		.100			2.54		
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32	
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68	
Base to Seating Plane	A1	.015			0.38			
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26	
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60	
Overall Length	D	.740	.750	.760	18.80	19.05	19.30	
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43	
Lead Thickness	с	.008	.012	.015	0.20	0.29	0.38	
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78	
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56	
Overall Row Spacing §	eB	.310	.370	.430	7.87	9.40	10.92	
Mold Draft Angle Top	α	5	10	15	5	10	15	
Mold Draft Angle Bottom	β	5	10	15	5	10	15	

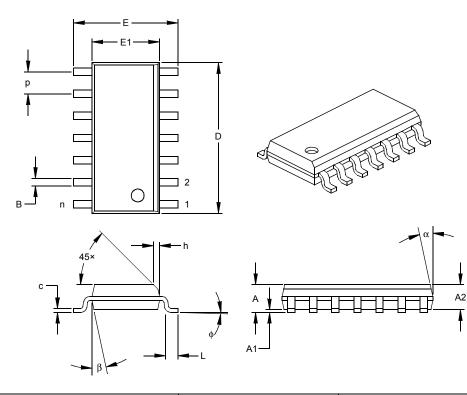
\* Controlling Parameter § Significant Characteristic

Notes: Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side. JEDEC Equivalent: MS-001 Drawing No. C04-005

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14-Lead Plastic Small Outline (SL) – Narrow, 150 mil (SOIC)



Units		INCHES*			MILLIMETERS		
Dimensi	on Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		14			14	
Pitch	р		.050			1.27	
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	Е	.228	.236	.244	5.79	5.99	6.20
Molded Package Width	E1	.150	.154	.157	3.81	3.90	3.99
Overall Length	D	.337	.342	.347	8.56	8.69	8.81
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.016	.033	.050	0.41	0.84	1.27
Foot Angle	φ	0	4	8	0	4	8
Lead Thickness	с	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.014	.017	.020	0.36	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

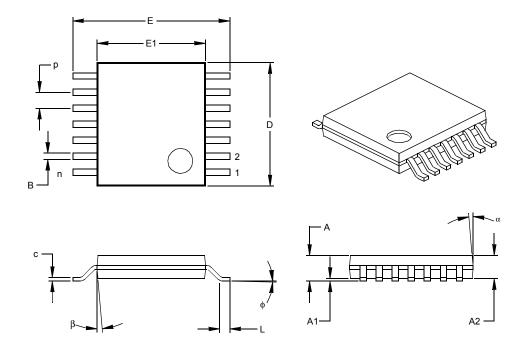
\* Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-012

Drawing No. C04-065

14-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm (TSSOP)



	Units		INCHES		MILLIMETERS*		*
Dimensio	on Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		14			14	
Pitch	р		.026			0.65	
Overall Height	Α			.043			1.10
Molded Package Thickness	A2	.033	.035	.037	0.85	0.90	0.95
Standoff §	A1	.002	.004	.006	0.05	0.10	0.15
Overall Width	Е	.246	.251	.256	6.25	6.38	6.50
Molded Package Width	E1	.169	.173	.177	4.30	4.40	4.50
Molded Package Length	D	.193	.197	.201	4.90	5.00	5.10
Foot Length	L	.020	.024	.028	0.50	0.60	0.70
Foot Angle	φ	0	4	8	0	4	8
Lead Thickness	с	.004	.006	.008	0.09	0.15	0.20
Lead Width	B1	.007	.010	.012	0.19	0.25	0.30
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

\* Controlling Parameter § Significant Characteristic

Notes: Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side. JEDEC Equivalent: MO-153 Drawing No. C04-087

#### **PRODUCT IDENTIFICATION SYSTEM**

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	<u>-X</u>	/XX	Exa	Examples:			
Device	 Temperature Range	Package	a)	MCP6546T-I/LT:	Tape and Reel, Industrial Temperature, 5LD SC-70.		
Device:		Single Comparator Single Comparator (Tape and Reel) (SC-70, SOT-23, SOIC, MSOP) Single Comparator (Rotated - Tape and	b)	MCP6546T-I/OT:	Tape and Reel, Industrial Temperature, 5LD SOT-23.		
			c)	MCP6546-I/P:	Industrial Temperature, 8LD PDIP.		
	MCP6547T:	Reel) (SOT-23 only) Dual Comparator Dual Comparator (Tape and Reel for SOIC and MSOP)	d)	MCP6546RT-I/OT	: Tape and Reel, Industrial Temperature, 5LD SOT23.		
	MCP6548T:	Single Comparator with CS Single Comparator with CS (Tape and Reel for SOIC and MSOP)	a)	MCP6547-I/MS:	Industrial Temperature, 8LD MSOP.		
	MCP6549: MCP6549T:	Quad Comparator Quad Comparator (Tape and Reel for SOIC and TSSOP)	b)	MCP6547T-I/MS:	Tape and Reel, Industrial Temperature, 8LD MSOP.		
Temperature Range: I = $-40^{\circ}$ C to $+85^{\circ}$ C			c)	MCP6547-I/P:	Industrial Temperature, 8LD PDIP.		
Package:		c Package (SC-70), 5-lead	a)	MCP6548-I/SN:	Industrial Temperature, 8LD SOIC.		
	MS = Plasti P = Plasti	c Small Outline Transistor (SOT-23), 5-lead c MSOP, 8-lead c DIP (300 mil Body), 8-lead, 14-lead c SOIC (150 mil Body), 8-lead	b)	MCP6548T-I/SN:	Tape and Reel, Industrial Temperature, 8LD SOIC.		
	SL = Plasti	c SOIC (150 mil Body), 14-lead (MCP6549) c TSSOP (4.4mm Body), 14-lead (MCP6549)	c)	MCP6548-I/P:	Industrial Temperature, 8LD PDIP.		
			a)	MCP6549T-I/SL:	Tape and Reel, Industrial Temperature, 14LD SOIC.		
			b)	MCP6549T-I/SL:	Tape and Reel, Industrial Temperature, 14LD SOIC.		
			c)	MCP6549-I/P:	Industrial Temperature, 14LD PDIP.		

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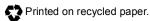
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